

# DC4800 | PCIe NVMe | OCP Cloud Spec 1.0

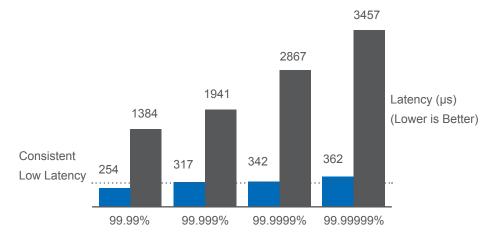
# Next-Generation Data Center SSDs for Fast, Cool, and Consistent Storage

SMART's DC4800 PCIe Gen4 NVMe SSDs are designed to meet the increasing demands placed on storage systems in Hyperscaler , Hyper converged, Enterprise, and Edge data centers.

SMART's DC4800 SSDs deliver industry leading KIOPs/Watt performance with superior Quality of Service (QoS) across mixed application workloads. At the heart of the DC4800 SSDs is an innovative controller and firmware architecture that delivers ultra-low and consistent I/O latency with power consumption levels that virtually eliminate thermal throttling.

### Superior Latency QoS <370µs at 99.99999%

- SMART DC4800 SSD
- Competitive SSD



Latency Percentile for 70/30 random 4K RW RW



### **Product Family Overview**

Form Factor	Capacity	
EDSFF E1.S	1.92TB, 3.84TB, 7.68TB	
U.2		

### Benefits of SMART Gen4 SSDs

- 7.1GB/s seq read, 4.6GB/s seq write,
   1.5M IOPS andom read, 180K IOPS random write
- Superior Qualify of Service (QoS) with 7 nines of latency consistency
- eTLC 3D NAND, 1 DWPD
- Up to 25% lower power than other Gen4 SSDs with industry leading KIOPs/Watt
- Leading edge, trusted industry security standards
- Open Compute Project (OCP) support

## **Key Features**

- Capacities: 1.92TB, 3.84TB, 7.68TB (7% OP)
- Security and Encryption: TCG OPAL 2.0, AES XTS 256, TRNG
- Secure Boot with ECDSA-256 and SHA3-512
- High Reliability: End to End data path protection, SRAM/DRAM ECC, Power Loss Protection
- Sector Size: 512, 4096
- Enhanced NAND level reliability: In storage RAID with LUN level protection, L2P Mapping Index Check, 4KB LDPC multi code rates
- Multiple Namespace (16)
- NVMe MI 1.0b, SMART and Health Logs/Telemetry
- OCP Cloud Spec 1.0

# **Specifications**

	EDSFF E1.S SSD	U.2 SSD	
NAND Type	eTLC		
Performance			
Host Interface Rate (maximum)	PCIe Gen4 x4		
Capacities	1.92TB, 3.84TB, 7.68TB		
Sequential Read (maximum)	Up to 7100MB	Up to 7100MB/s	
Sequential Write (maximum)	Up to 4600MB	Up to 4600MB/s	
Random Read Performance (KIOPS)	Up to 1490K IOPS  Up to 180K IOPS  80		Thread Count = 1 Queue Depth = 128 IO Size = 4KB Sustained Thread Count = 1 Queue Depth = 1
Random Write Performance (KIOPS)			
Random Read Latency (μs)			
Random Write Latency (µs)	15		IO Size = 4KB Typical
Latency QoS (99.9%) (Queue Depth 1   64)			
99.9% QoS – Random Read (μs)	110   240		Thread Count = 1  Queue Depth = 1   64
99.9% QoS – Random Write (μs)	30   1200	30   1000	IO Size = 4KB
Electrical Specification			
Supply Voltage Min   Max (V)	10.8   13.2		
Active Power Consumption (W)	< 13		
Idle Power Consumption (W)	<1.0		
Reliability, Mechanical			
MTBF (Hours)	2M		
UBER	1 Sector per 10 <sup>17</sup> Read		
Retention	2 Months @ 40°C (EOL)		
DWPD 5 yrs 7% OP	1		
Enclosure	5.9, 9.5, 15, 25mm	15mm	_



For more information, please visit: www.smartm.com

\*Product images are for promotional purposes only. Labels may not be representative of the actual product.

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